ROITHNER LASERTECHNIK

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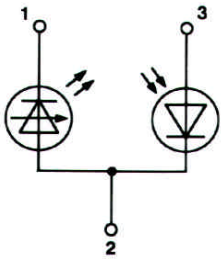
RLT9810G TECHNICAL DATA

Infrared Laserdiode

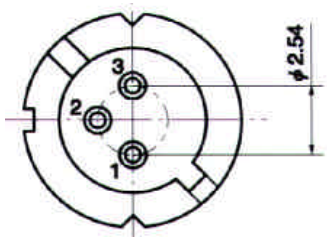
Lasing wavelength: **980 nm typ., single mode**
Max. optical power: **12 mW**
Package: **9 mm, SOT-148**

NOTE!
LASERDIODE
MUST BE COOLED!

PIN CONNECTION:



1) Laser diode cathode
2) Laser diode anode and photodiode cathode
3) Photodiode anode



Absolute Maximum Ratings (Tc=25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Optical Output Power	P_o	12	mW
LD Reverse Voltage	$V_{R(LD)}$	0.5	V
PD Reverse Voltage	$V_{R(PD)}$	5	V
Operation Case Temperature	T_C	-20 .. +40	°C
Storage Temperature	T_{STG}	-60 .. +70	°C

Optical-Electrical Characteristics (Tc = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Optical Output Power	P_o	-		10		mW
Threshold Current	I_{th}	-	15	25	35	mA
Operation Current	I_{op}	P_o = 10 mW		35	60	mA
Operating Voltage	V_{op}	P_o = 10 mW	1.4	1.5	1.8	V
Lasing Wavelength	λ	P_o = 10 mW	970	980	990	nm
Beam Divergence	$\theta_{//}$	P_o = 10 mW	6	8	12	°
Beam Divergence	$\theta_{\perp}$	P_o = 10 mW	25	30	35	°
Emitting Aperture	A	-	1 x 2	1 x 3	1 x 4	µm
Monitor Current	I_m	P_o = 10 mW	50	100		µA